Integrated Device Technology, Inc.

FAST CMOS OCTAL D FLIP-FLOP WITH CLOCK ENABLE

IDT54/74FCT377
IDT54/74FCT377A
IDT54/74FCT377C

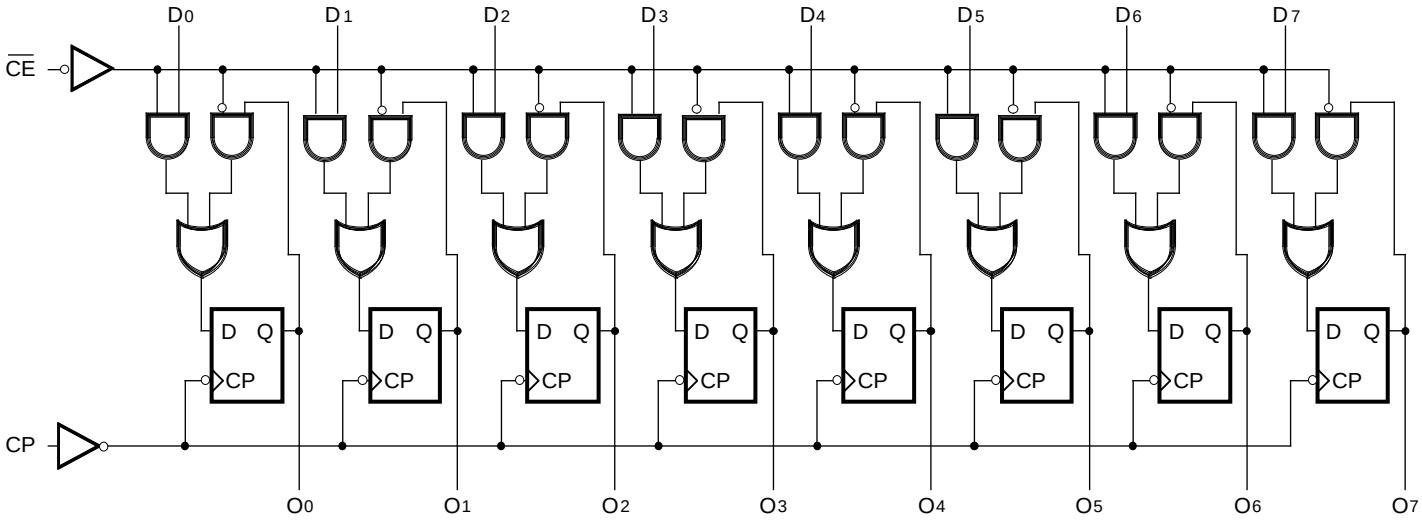
FEATURES:

- IDT54/74FCT377 equivalent to FAST™ speed
- **IDT54/74FCT377A 25% faster than FAST**
- **IDT54/74FCT377C 40% faster than FAST**
- Equivalent to FAST output drive over full temperature and voltage supply extremes
- I_{OL} = 48mA (commercial) and 32mA (military)
- I_{IH} and I_{IL} only 5µA max.
- CMOS power levels (1mW typ. static)
- CMOS output level compatible
- Meets or exceeds JEDEC Standard 18 specifications
- Product available in Radiation Tolerant and Radiation Enhanced versions
- Military product compliant to MIL-STD-883, Class B

DESCRIPTION:

The IDT54/74FCT377/A/C is an octal D flip-flop built using an advanced dual metal CMOS technology. The IDT54/74FCT377/A/C have eight edge-triggered, D-type flip-flops with individual D inputs and O outputs. The common buffered Clock (CP) input loads all flip-flops simultaneously when the Clock Enable ($\overline{CE}$) is LOW. The register is fully edge-triggered. The state of each D input, one set-up time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's O output. The $\overline{CE}$ input must be stable only one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

FUNCTIONAL BLOCK DIAGRAM



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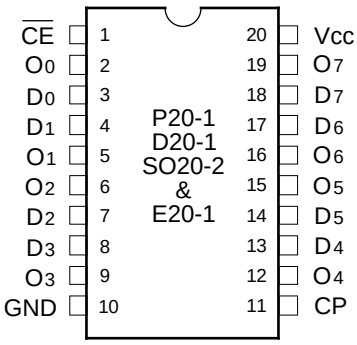
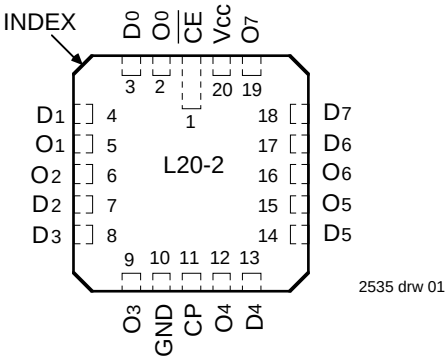
PIN CONFIGURATIONS



DIP/SOIC/CERPACK
TOP VIEW



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LCC
TOP VIEW

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PIN DESCRIPTION

Pin Names	Description
D_0–D_7	Data Inputs
$\overline{CE}$	Clock Enable (Active LOW)
O_0–O_7	Data Outputs
CP	Clock Pulse Input

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FUNCTION TABLE(1)

Operating Mode	Inputs			Outputs
	CP	$\overline{CE}$	D	O
Load "1"	↑	l	h	H
Load "0"	↑	l	l	L
Hold (Do Nothing)	↑	h	X	No Change
	H	H	X	No Change

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NOTE:
1. H = HIGH voltage level
   h = HIGH voltage level one set-up time prior to the LOW-to-HIGH Clock Transition
   L = LOW voltage level
   l = LOW voltage level one set-up time prior to the LOW-to-HIGH Clock transition
   X = Immaterial
   ↑ = LOW-to-HIGH clock transition

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Rating	Commercial	Military	Unit
V_{TERM}(2)	Terminal Voltage with Respect to GND	–0.5 to +7.0	–0.5 to +7.0	V
V_{TERM}(3)	Terminal Voltage with Respect to GND	–0.5 to V_{CC}	–0.5 to V_{CC}	V
T_A	Operating Temperature	0 to +70	–55 to +125	°C
T_{BIAS}	Temperature Under Bias	–55 to +125	–65 to +135	°C
T_{STG}	Storage Temperature	–55 to +125	–65 to +150	°C
P_T	Power Dissipation	0.5	0.5	W
I_{OUT}	DC Output Current	120	120	mA

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NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed V_{CC} by +0.5V unless otherwise noted.
2. Input and V_{CC} terminals only.
3. Outputs and I/O terminals only.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter(1)	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	6	10	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	8	12	pF

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NOTE:
1. This parameter is guaranteed but not tested.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: V_{LC} = 0.2V; V_{HC} = V_{CC} – 0.2V
Commercial: T_A = 0°C to +70°C, V_{CC} = 5.0V ± 5%; Military: T_A = –55°C to +125°C, V_{CC} = 5.0V ± 10%

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
V_{IH}	Input HIGH Level	Guaranteed Logic HIGH Level		2.0	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I_{IH}	Input HIGH Current	V_{CC} = Max.	V_I = V_{CC}	—	—	5	µA
			V_I = 2.7V	—	—	5[4]	
I_{IL}	Input LOW Current		V_I = 0.5V	—	—	–5[4]	
			V_I = GND	—	—	–5	
V_{IK}	Clamp Diode Voltage	V_{CC} = Min., I_N = –18mA		—	–0.7	–1.2	V
I_{OS}	Short Circuit Current	V_{CC} = Max.[3], V_O = GND		–60	–120	—	mA
V_{OH}	Output HIGH Voltage	V_{CC} = 3V, V_{IN} = V_{LC} or V_{HC}, I_{OH} = –32µA		V_{HC}	V_{CC}	—	V
		V_{CC} = Min.	I_{OH} = –300µA	V_{HC}	V_{CC}	—	
		V_{IN} = V_{IH} or V_{IL}	I_{OH} = –12mA MIL.	2.4	4.3	—	
			I_{OH} = –15mA COM'L.	2.4	4.3	—	
V_{OL}	Output LOW Voltage	V_{CC} = 3V, V_{IN} = V_{LC} or V_{HC}, I_{OL} = 300µA		—	GND	V_{LC}	V
		V_{CC} = Min.	I_{OL} = 300µA	—	GND	V_{LC}[4]	
		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 32mA MIL.	—	0.3	0.5	
			I_{OL} = 48mA COM'L.	—	0.3	0.5	

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NOTES:
1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the short circuit test should not exceed one second.
4. This parameter is guaranteed but not tested.

POWER SUPPLY CHARACTERISTICS

V_{LC} = 0.2V; V_{HC} = V_{CC} – 0.2V

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
I_{CC}	Quiescent Power Supply Current	V_{CC} = Max. $V_{IN} \geq V_{HC}$; $V_{IN} \leq V_{LC}$		—	0.2	1.5	mA
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	Vcc = Max. V_{IN} = 3.4V[3]		—	0.5	2.0	mA
I_{CCD}	Dynamic Power Supply Current[4]	Vcc = Max. Outputs Open $\overline{CE}$ = GND One Input Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq V_{LC}$	—	0.15	0.25	mA/ MHz
I_C	Total Power Supply Current[6]	Vcc = Max. Outputs Open f_{CP} = 10MHz 50% Duty Cycle $\overline{CE}$ = GND One Bit Toggling at fi = 5MHz 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq V_{LC}$ (FCT)	—	1.7	4.0	mA
			V_{IN} = 3.4V V_{IN} = GND	—	2.2	6.0	
		V_{CC} = Max. Outputs Open f_{CP} = 10MHz 50% Duty Cycle $\overline{CE}$ = GND Eight Bits Toggling at f_i = 2.5MHz 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq V_{LC}$ (FCT)	—	4.0	7.8[5]	
			V_{IN} = 3.4V V_{IN} = GND	—	6.2	16.8[5]	

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NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5.0V, +25°C ambient.
3. Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
4. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
   $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$
   I_{CC} = Quiescent Current
   ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)
   D_H = Duty Cycle for TTL Inputs High
   N_T = Number of TTL Inputs at D_H
   I_{CCD} = Dynamic Current Caused by an Output Transition Pair (HLH or LHL)
   f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)
   f_i = Input Frequency
   N_i = Number of Inputs at f_i
   All currents are in milliamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Condition[1]	IDT54/74FCT377				IDT54/74FCT377A				IDT54/74FCT377C				Unit
			Com'l.		Mil.		Com'l.		Mil.		Com'l.		Mil.		
			Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	
t_{PLH} t_{PHL}	Propagation Delay CP to On	C_L = 50pF R_L = 500Ω	2.0	13.0	2.0	15.0	2.0	7.2	2.0	8.3	2.0	5.2	2.0	5.5	ns
t_{SU}	Set-up Time HIGH or LOW Dn to CP		2.5	—	3.0	—	2.0	—	2.0	—	2.0	—	2.0	—	ns
t_H	Hold Time HIGH or LOW Dn to CP		2.0	—	2.5	—	1.5	—	1.5	—	1.5	—	1.5	—	ns
t_{SU}	Set-up Time HIGH or LOW $\overline{CE}$ to CP		4.0	—	4.0	—	3.5	—	3.5	—	3.5	—	3.5	—	ns
t_H	Hold Time HIGH or LOW $\overline{CE}$ to CP		1.5	—	1.5	—	1.5	—	1.5	—	1.5	—	1.5	—	ns
t_W	Clock Pulse Width, HIGH or LOW		7.0	—	7.0	—	6.0	—	7.0	—	6.0	—	7.0	—	ns

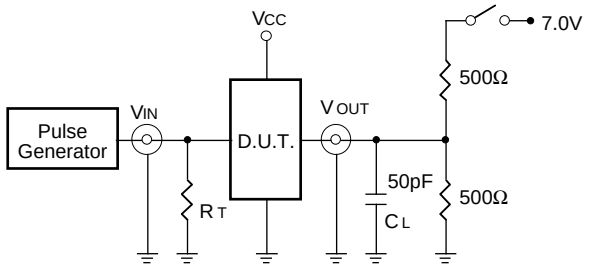
NOTES:

2535 tbl 07

1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.

TEST CIRCUITS AND WAVEFORMS

TEST CIRCUITS FOR ALL OUTPUTS



SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

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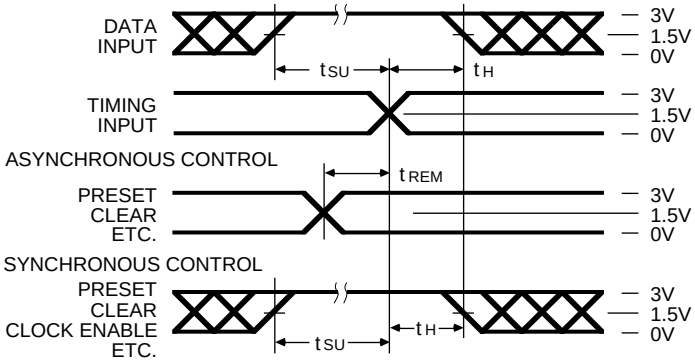
DEFINITIONS:

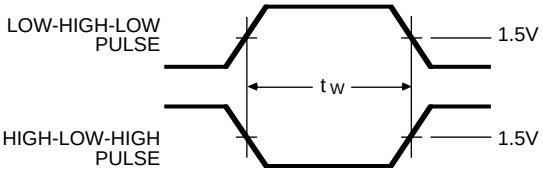
C_L = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

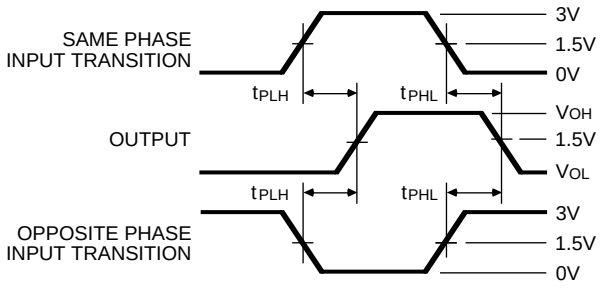
SET-UP, HOLD AND RELEASE TIMES



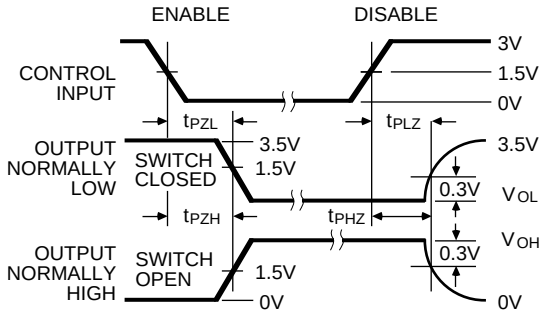
PULSE WIDTH



PROPAGATION DELAY



ENABLE AND DISABLE TIMES



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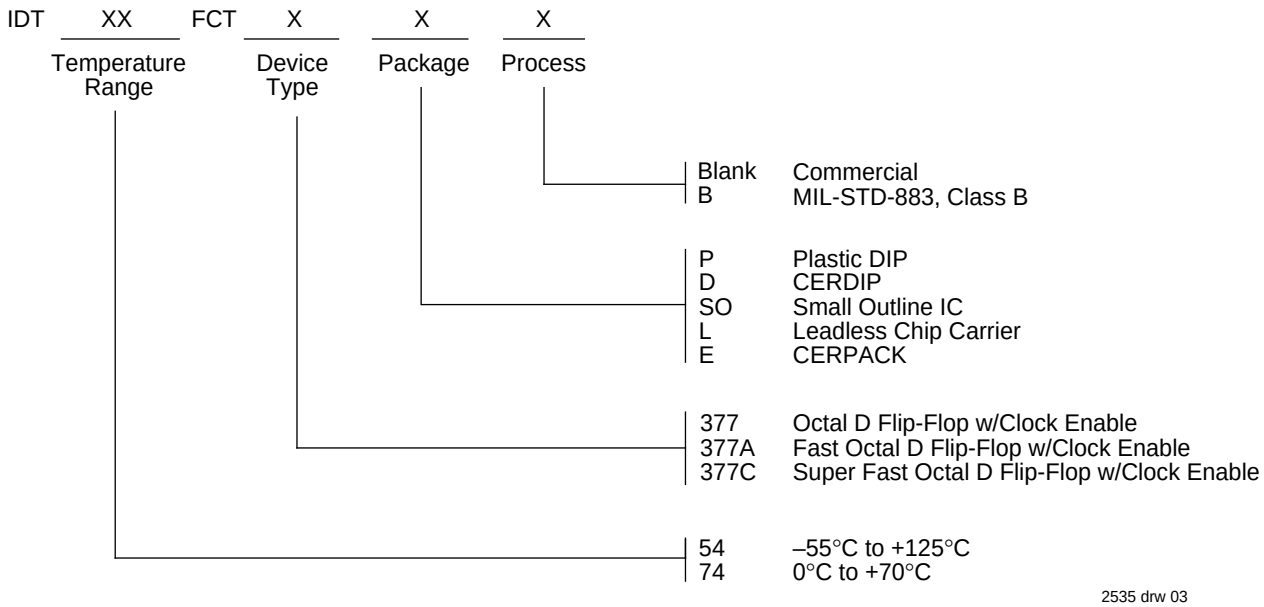
NOTES

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
2. Pulse Generator for All Pulses: Rate ≤ 1.0 MHz; $Z_O \leq 50\Omega$; $t_F \leq 2.5$ns; $t_R \leq 2.5$ns.

ORDERING INFORMATION



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